# Silicon Carbide Schottky Diode

# 1200 V, 10 A

# FFSH10120A-F085

# Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size & cost.

# Features

- Max Junction Temperature 175°C
- Avalanche Rated 100 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

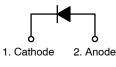
# Applications

- Automotive HEV-EV Onboard Chargers
- Automotive HEV-EV DC-DC Converters



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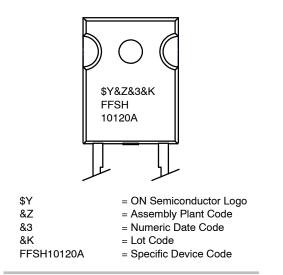


Schottky Diode



10-247-2LD CASE 340CL

# MARKING DIAGRAM



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# FFSH10120A-F085

| Symbol                            | Parameter   | Value                                    | Unit        |    |
|-----------------------------------|---|--|-------------|----|
| V <sub>RRM</sub>                  | Peak Repetitive Reverse Voltage                               |  | 1200        | V  |
| E <sub>AS</sub>                   | Single Pulse Avalanche Energy (Note 1)                        |  | 100         | mJ |
| ١ <sub>F</sub>                    | Continuous Rectified Forward Current @ T <sub>C</sub> < 158°C |  | 10          | A  |
|                                   | Continuous Rectified Forward Current @ T <sub>C</sub> < 135°C |  | 17          |    |
| I <sub>F, Max</sub>               | Non-Repetitive Peak Forward Surge Current                     | T <sub>C</sub> = 25°C, 10 μs             | 850         | А  |
|                                   |   | T <sub>C</sub> = 150°C, 10 μs            | 800         | А  |
| I <sub>F,SM</sub>                 | Non-Repetitive Forward Surge Current                          | Half-Sine Pulse, t <sub>p</sub> = 8.3 ms | 90          | А  |
| I <sub>F,RM</sub>                 | Repetitive Forward Surge Current                              | Half-Sine Pulse, t <sub>p</sub> = 8.3 ms | 35          | А  |
| Ptot                              | Power Dissipation   | $T_{\rm C} = 25^{\circ}{\rm C}$          | 193         | W  |
|                                   |   | T <sub>C</sub> = 150°C                   | 32          | W  |
| T <sub>J</sub> , T <sub>STG</sub> | Operating and Storage Temperature Range                       |  | -55 to +175 | °C |
|                                   | TO-247 Mounting Torque, M3 Screw                              | 60                                       | Ncm         |    |

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1.  $E_{AS}$  of 100 mJ is based on starting  $T_J = 25^{\circ}$ C, L = 0.5 mH,  $I_{AS} = 20$  A, V = 50 V.

#### **THERMAL CHARACTERISTICS**

| Symbol          | Parameter                                 | Value | Unit |
|-----------------|---|-------|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case, Max | 0.78  | °C/W |

# **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

| Symbol         | Parameter               | Test Condition   | Min | Тур  | Max  | Unit |
|----------------|-------------------------|--|-----|------|------|------|
| V <sub>F</sub> | Forward Voltage         | I <sub>F</sub> = 10 A, T <sub>C</sub> = 25°C                 | -   | 1.45 | 1.75 | V    |
|                |                         | I <sub>F</sub> = 10 A, T <sub>C</sub> = 125°C                | -   | 1.7  | 2.0  |      |
|                |                         | I <sub>F</sub> = 10 A, T <sub>C</sub> = 175°C                | -   | 2.0  | 2.4  |      |
| I <sub>R</sub> | Reverse Current         | $V_{R} = 1200 \text{ V}, \text{ T}_{C} = 25^{\circ}\text{C}$ | -   | -    | 200  | μΑ   |
|                |                         | $V_{R}$ = 1200 V, $T_{C}$ = 125°C                            | -   | -    | 300  |      |
|                |                         | $V_{R}$ = 1200 V, $T_{C}$ = 175°C                            | -   | -    | 400  |      |
| Q <sub>C</sub> | Total Capacitive Charge | V = 800 V  | -   | 62   | -    | nC   |
| С              | Total Capacitance       | V <sub>R</sub> = 1 V, f = 100 kHz                            | -   | 612  | -    | pF   |
|                |                         | V <sub>R</sub> = 400 V, f = 100 kHz                          | -   | 58   | -    | 1    |
|                |                         | V <sub>R</sub> = 800 V, f = 100 kHz                          | -   | 47   | _    |      |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

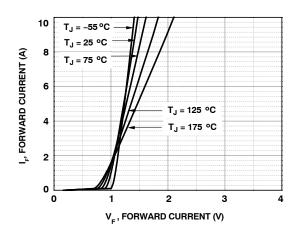
### **ORDERING INFORMATION**

| Part Number     | Top Marking | Package                                | Shipping        |  |
|-----------------|-------------|--|-----------------|--|
| FFSH10120A-F085 | FFSH10120A  | TO-247-2LD<br>(Pb-Free / Halogen Free) | 30 Units / Tube |  |

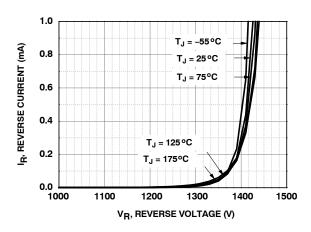
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# **TYPICAL CHARACTERISTICS**

(T<sub>J</sub> = 25°C unless otherwise noted)



**Figure 1. Forward Characteristics** 



**Figure 3. Reverse Characteristics** 

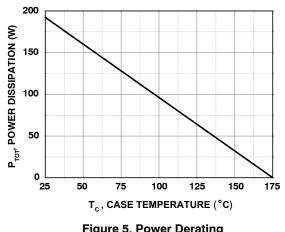


Figure 5. Power Derating

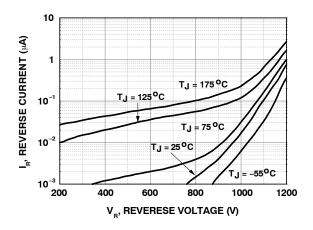
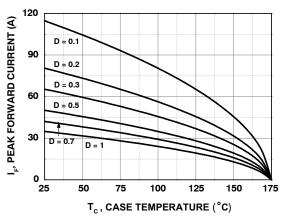
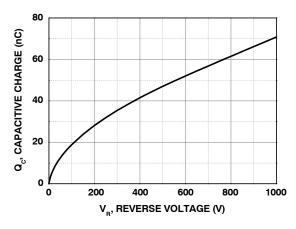


Figure 2. Reverse Characteristics



**Figure 4. Current Derating** 





# FFSH10120A-F085

# **TYPICAL CHARACTERISTICS**

(T<sub>J</sub> =  $25^{\circ}$ C unless otherwise noted)

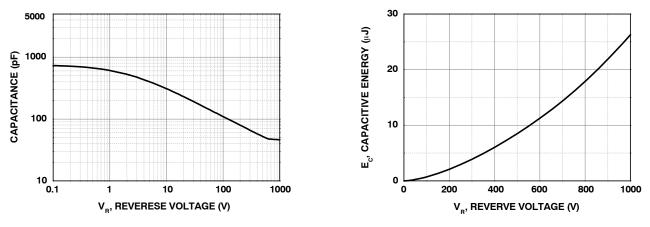


Figure 7. Capacitance vs. Reverse Voltage

Figure 8. Capacitance Stored Energy

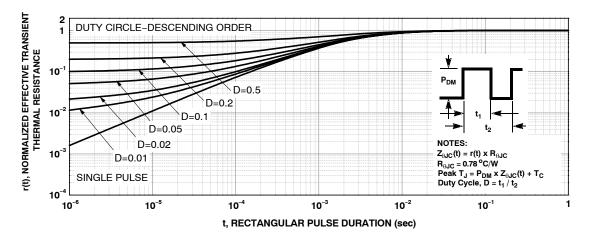


Figure 9. Junction-to-Case Transient Thermal Response Curve

# **TEST CIRCUIT AND WAVEFORMS**

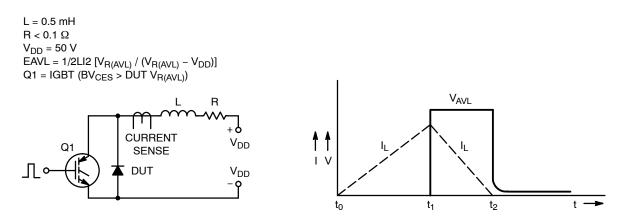


Figure 10. Unclamped Inductive Switching Test Circuit & Waveform

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**MILLIMETERS** 

NOM

4.70

2.40

1.50

1.26

1.65

0.61

20.57

16.57

0.93

15.62

~

5.08

11.12

16.00

3.81

3.58

6.73

5.46

5.46

MAX

4.82

2.66

1.70

1.35

1.77

0.71

20.82

16.77

1.35

15.87

~

5.20

~

16.25

3.93

3.65

6.85

5.58

5.58

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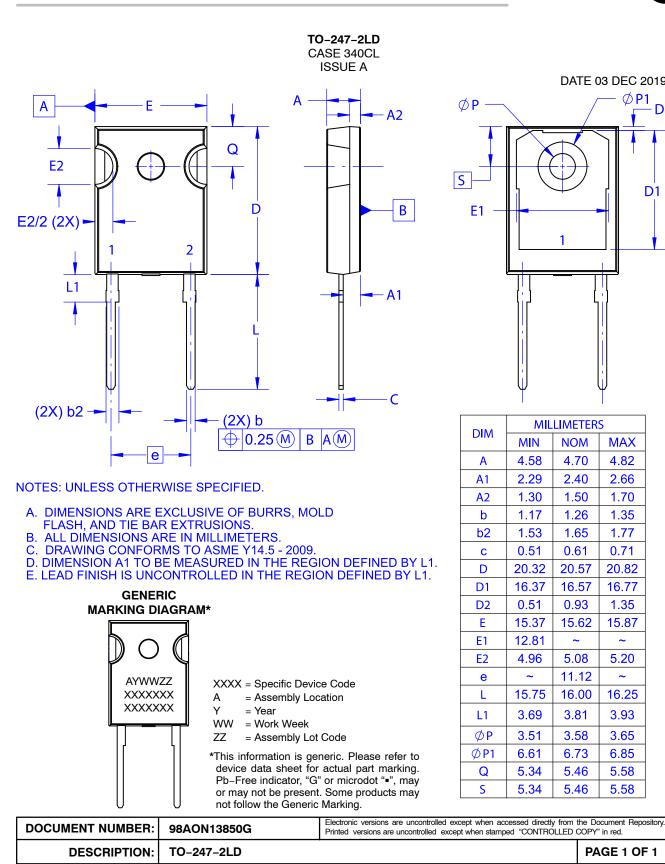
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ØP1



D2

D1



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